捷多邦,专业PCB打样工厂,24小时加急出货



Silicon P Channel MOS FET WWW.0ZS

查询2SJ545-E供应商

REJ03G0892-0400 Rev.4.00 Jun 05, 2006

### Description

High speed power switching

### **Features**

- Low on-resistance
- Low drive current
- •
- • High speed switching

# Outline

RENESAS Package code: PRSS0003AE-A (Package name: TO-220C•FM) D 1. Gate GC 2. Drain 3. Source Ċ 2 S

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# **Absolute Maximum Ratings**

			$(Ta = 25^{\circ}C)$
Item	Symbol	Value	Unit
Drain to source voltage	V <sub>DSS</sub>	-60	V
Gate to source voltage	V <sub>GSS</sub>	±20	V
Drain current	Ι <sub>D</sub>	-12	A
Drain peak current	I <sub>D (pulse)</sub> Note 1	-48	A
Body to drain diode reverse drain current	I <sub>DR</sub>	-12	A
Avalanche current	I <sub>AP</sub> Note 3	-12	A
Avalanche energy	E <sub>AR</sub> Note 3	12	mJ
Channel dissipation	Pch Note 2	25	W
Channel temperature	Tch	150	۵°
Storage temperature	Tstg	-55 to +150	۵°

Notes: 1.  $PW \le 10 \ \mu s$ , duty cycle  $\le 1\%$ 

2. Value at Tc =  $25^{\circ}C$ 

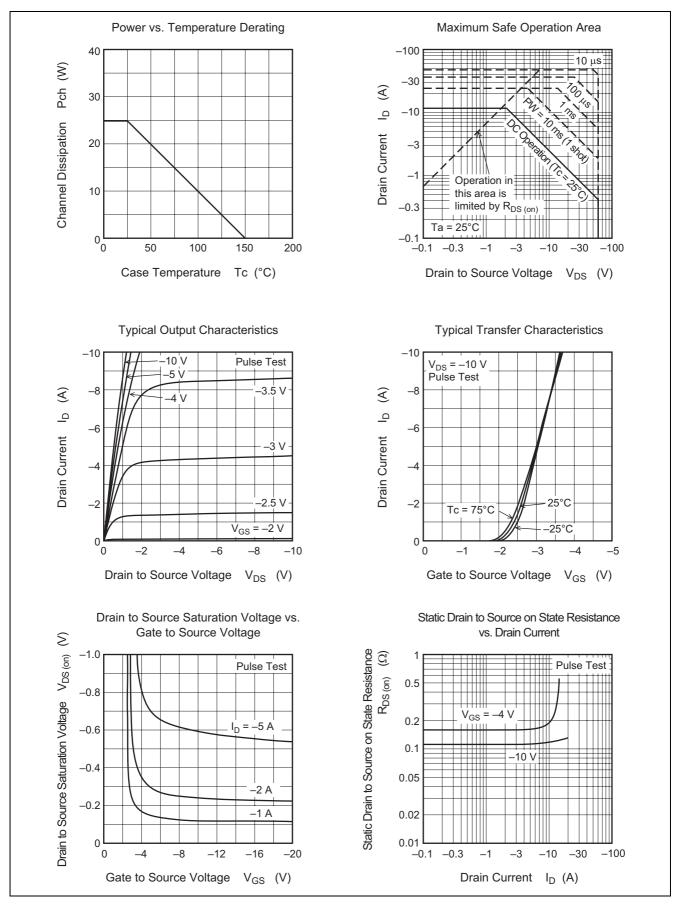
3. Value at Tch =  $25^{\circ}$ C, Rg  $\geq 50 \Omega$ 

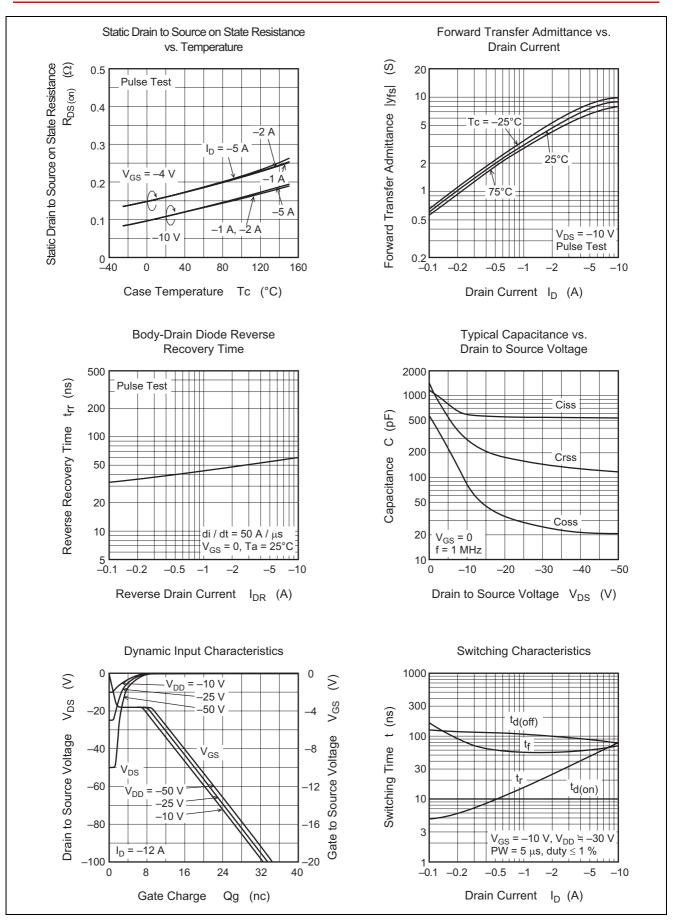
# **Electrical Characteristics**

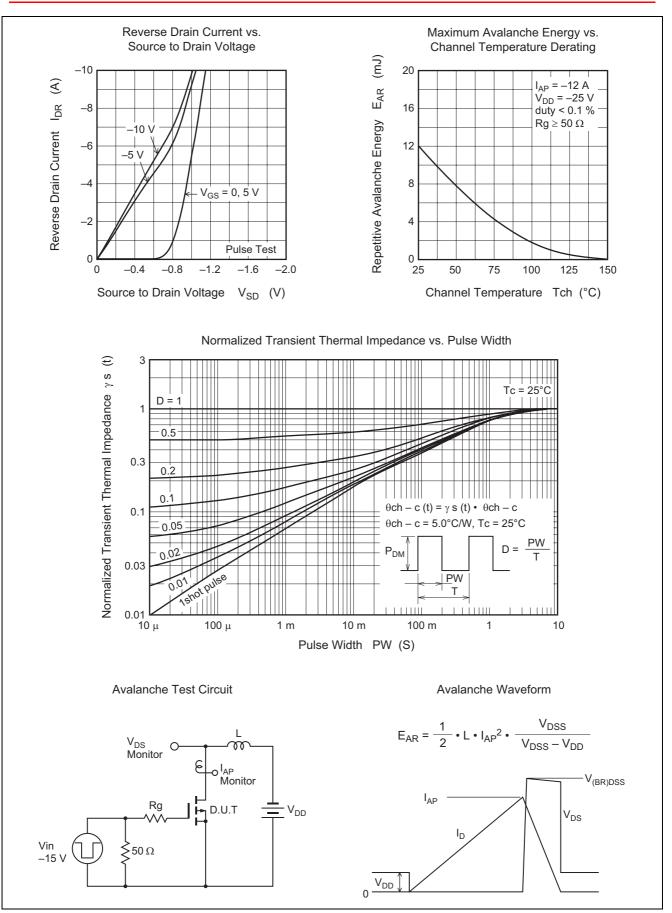
						$(Ta = 25^{\circ}C)$
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	V (BR) DSS	-60			V	$I_D = -10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	V (BR) GSS	±20		—	V	$I_{G} = \pm 100 \ \mu A, \ V_{DS} = 0$
Zero gate voltage drain current	I <sub>DSS</sub>	_		-10	μΑ	$V_{DS} = -60 \text{ V}, \text{ V}_{GS} = 0$
Gate to source leak current	I <sub>GSS</sub>	_		±10	μΑ	$V_{GS} = \pm 16 \text{ V}, \text{ V}_{DS} = 0$
Gate to source cutoff voltage	V <sub>GS (off)</sub>	-1.0		-2.0	V	$I_D = -1 \text{ mA}, V_{DS} = -10 \text{ V}$
Static drain to source on state resistance	R <sub>DS (on)</sub>	_	0.11	0.15	Ω	$I_D = -6 \text{ A}, V_{GS} = -10 \text{ V}^{\text{Note 4}}$
	R <sub>DS (on)</sub>		0.16	0.23	Ω	$I_D = -6 \text{ A}, V_{GS} = -4 \text{ V}^{\text{Note 4}}$
Forward transfer admittance	y <sub>fs</sub>	5	8	_	S	$I_D = -6 \text{ A}, V_{DS} = -10 \text{ V}^{\text{Note 4}}$
Input capacitance	Ciss	_	580	_	pF	$V_{DS} = -10 \text{ V}$
Output capacitance	Coss		300		pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	—	85	_	pF	f = 1 MHz
Turn-on delay time	t <sub>d (on)</sub>	_	10	—	ns	$V_{GS} = -10 \text{ V}$
Rise time	t <sub>r</sub>		55		ns	$I_{\rm D} = -6  {\rm A}$
Turn-off delay time	t <sub>d (off)</sub>		85		ns	$R_L = 6 \Omega$
Fall time	t <sub>f</sub>		60		ns	
Body to drain diode forward voltage	V <sub>DF</sub>	—	-1.2		V	$I_F = -12 \text{ A}, V_{GS} = 0$
Body to drain diode reverse recovery time	t <sub>rr</sub>	—	60	—	ns	$I_F = -12 \text{ A}, V_{GS} = 0$
						di <sub>F</sub> /dt = 50 A/µs

Note: 4. Pulse test

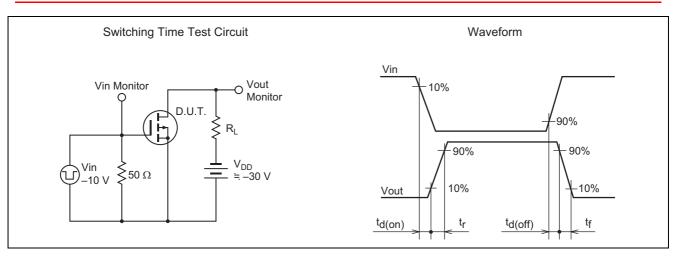
### **Main Characteristics**



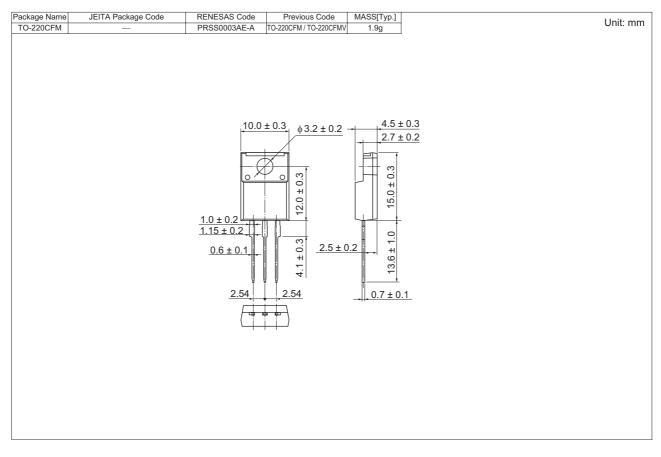




### 2SJ545



# **Package Dimensions**



# **Ordering Information**

Part Name	Quantity	Shipping Container			
2SJ545-E 600 pcs		Box (Tube)			
Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of					

production before ordering the product.

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